

### SEMICONDUCTOR

# SOD882 Plastic Package **Transient Voltage Suppressors ESD** Protection Diode

#### Absolute Maximum Ratings T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
PD	Total Power Dissipation on FR-5 Broad	150	mW
TL	Max Lead Solder Temperature range (10 Second Duration)	260	°C
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C
TJ	Junction Temperature	+150	°C
ESD	IEC61000-4-2 Air Discharge Contact Discharge	土15 土8	KV
EFT	IEC61000-4-4	40	А
ESD	Per Human Body Model	16	KV

These ratings are limiting values above which the serviceability of the diode may be impaired.

### **Specification Features:**

- § Ultra Low Capacitance Typ. 0.9pF
- § Low Clamping Voltage
- Small Body Outline Dimensions
- **လ** လ လ လ လ လ လ Low Leakage Current
  - Response Time is Typically < 1ns
  - ESD Rating of Class 3 (>16kV) per Human Body Model
- **RoHS** Compliant
- Green EMC
- Matte Tin(Sn) Lead Finish
- § Weight: approx. 0.001g

## **Electrical Parameter**

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
Ι <sub>Τ</sub>	Test Current
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>

Green Product



SOD882 Package



ELECTRICAL SYMBOL

**DEVICE MARKING CODES:** 

Device Type	Marking	Shipping
ESD8L5V0C		10,000/Reel





#### SEMICONDUCTOR

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	Device Type	V <sub>RWM</sub> (Volts)	<b>Ι<sub>R</sub> @ V<sub>RWM</sub></b> (μΑ)	V <sub>BR</sub> (No (Vo	@ <b>I<sub>T</sub></b> te 1) blts)	Ι <sub>τ</sub> (mA)	V <sub>C</sub> @ Max I <sub>PP</sub> (Volts)	<b>І<sub>РР</sub>*</b> (А)	C @ V <sub>R</sub> = 0V, f = 1MHz (pF)
Max Max Min Max Max Max Max Typ.		Max	Max	Min	Max		Max	Max	Тур.
ESD8L5V0C 5.0 1 5.4 1.0 12.9 1 0.9	ESD8L5V0C	5.0	1	5.4		1.0	12.9	1	0.9

#### 25°C unless otherwise noted) **Electrical Characteristics** (T)

\* Surge current waveform per Figure 1. Note 1:  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C.

#### SURGE CURRENT WAVEFORM:





#### SOD882 Package Outline



DIM	MILLIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
А	0.46	0.50	0.018	0.020	
A1		0.03		0.001	
b	0.45	0.55	0.018	0.022	
D	0.55	0.65	0.022	0.026	
Е	0.95	1.05	0.037	0.041	
e1	Тур. 0.65		Тур. 0.026		
L	0.20	0.30	0.008	0.012	



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